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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# 2SJ217

## Silicon P Channel MOS FET

REJ03G0850-0200 (Previous: NON-084)

> Rev.2.00 Sep 07, 2005

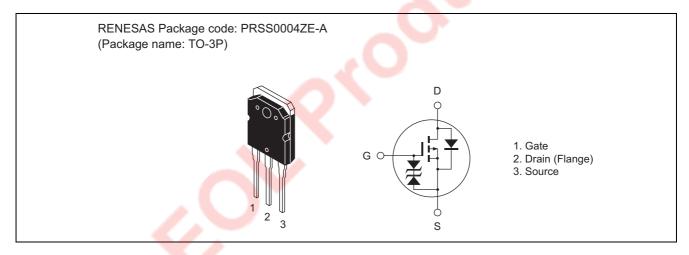
### **Description**

High speed power switching

### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	$V_{DSS}$	-60	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	I <sub>D</sub>	-45	A
Drain peak current	I <sub>D (pulse)</sub> Note 1	-180	A
Body to drain diode reverse drain current	I <sub>DR</sub>	-45	Α
Channel dissipation	Pch Note 2	150	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at  $Tc = 25^{\circ}C$ 

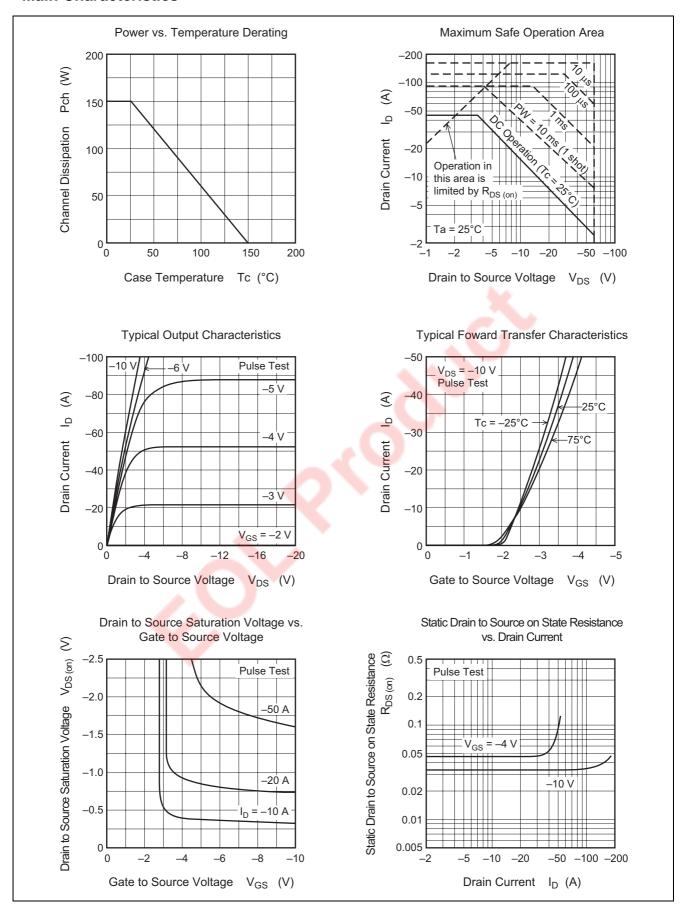
### **Electrical Characteristics**

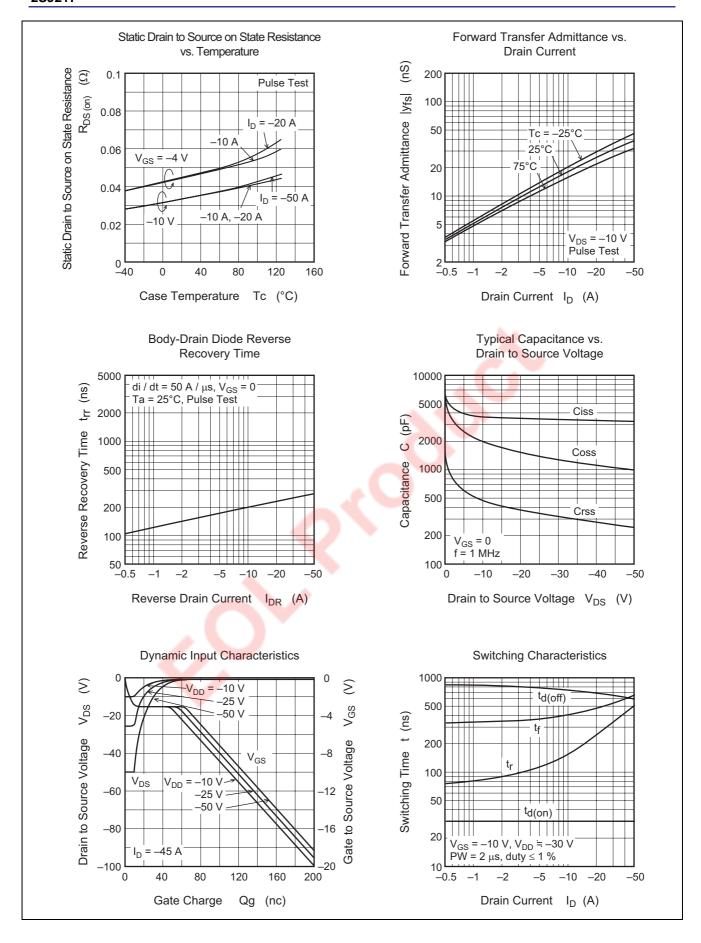
 $(Ta = 25^{\circ}C)$ 

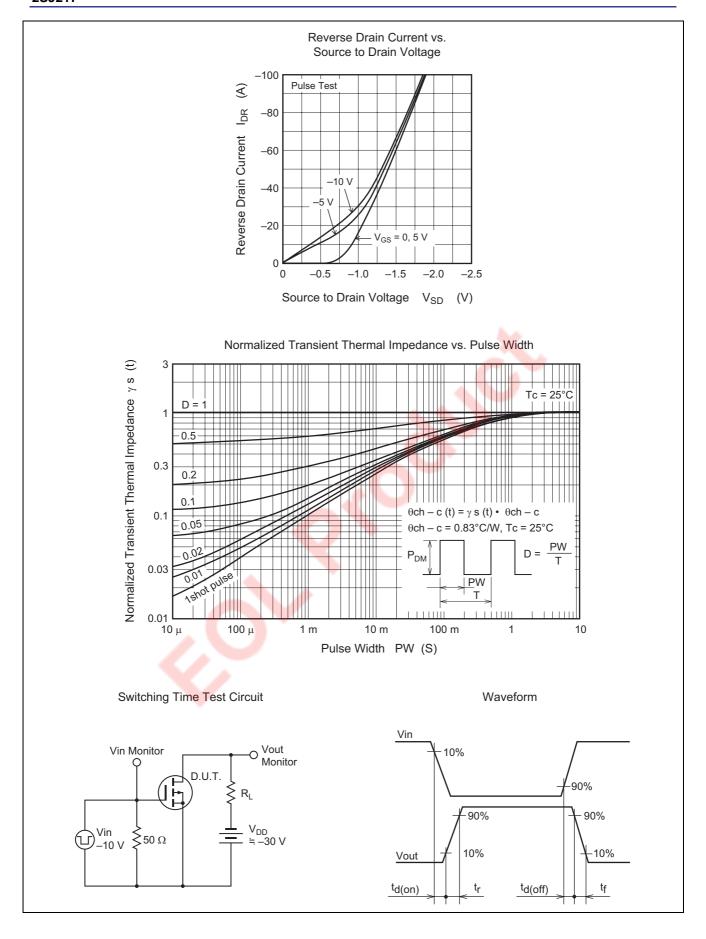
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR) GSS</sub>	±20	_	_	V	$I_G = \pm 100 \mu\text{A},  V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	-250	μΑ	$V_{DS} = -50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-1.0	_	-2.0	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.033	0.042	Ω	$I_D = -20 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 3}}$
	R <sub>DS (on)</sub>		0.045	0.06	Ω	$I_D = -20 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y <sub>fs</sub>	16	25	_	S	$I_D = -20 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 3}}$
Input capacitance	Ciss	$\sim$	3800	_	pF	V <sub>DS</sub> = -10 V
Output capacitance	Coss	9 0	2000	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	490	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	_	30	_	ns	$I_D = -20 \text{ A}$
Rise time	t <sub>r</sub>	_	235	_	ns	V <sub>GS</sub> = -10 V
Turn-off delay time	t <sub>d (off)</sub>	_	670	_	ns	$R_L = 1.5 \Omega$
Fall time	t <sub>f</sub>	_	450	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	-1.35	_	V	$I_F = -45 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>	_	300	_	ns	$I_F = -45 \text{ A}, V_{GS} = 0$
						$di_F/dt = 50 A/\mu s$

Note: 3. Pulse test

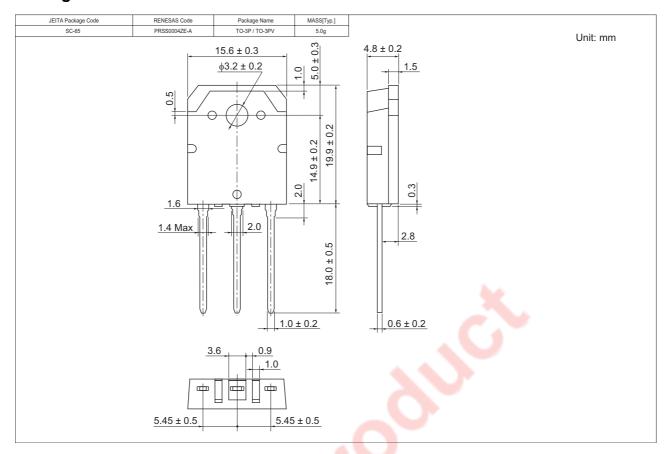
### **Main Characteristics**







### **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SJ217-E	30 pcs	Plastic magazine

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